

# **Device Modeling Report**

**COMPONENTS:**

**DIODE/ SCHOTTKY RECTIFIER**

**PART NUMBER: 30WQ04FN**

**MANUFACTURER: INTERNATIONAL RECTIFIER**

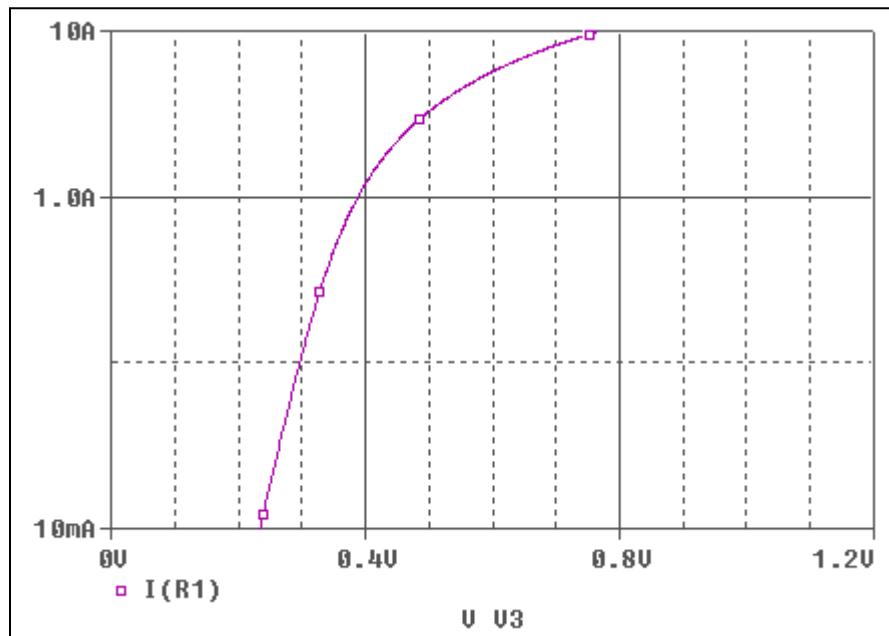


**Bee Technologies Inc.**

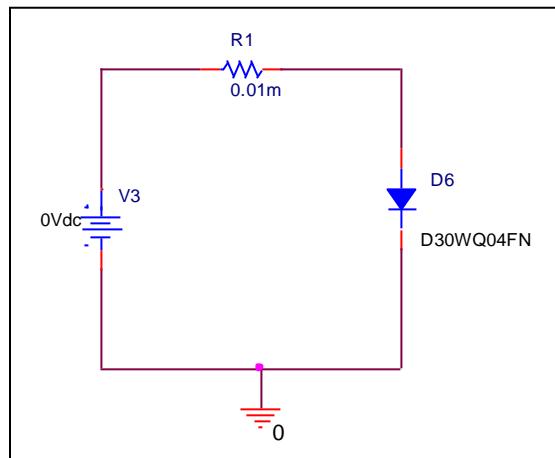
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

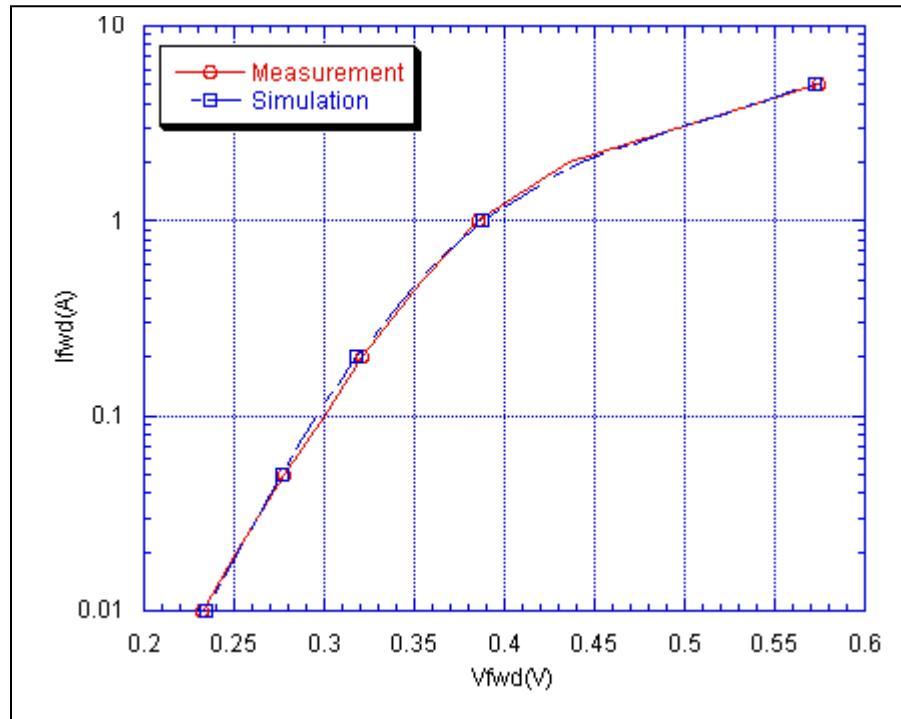


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

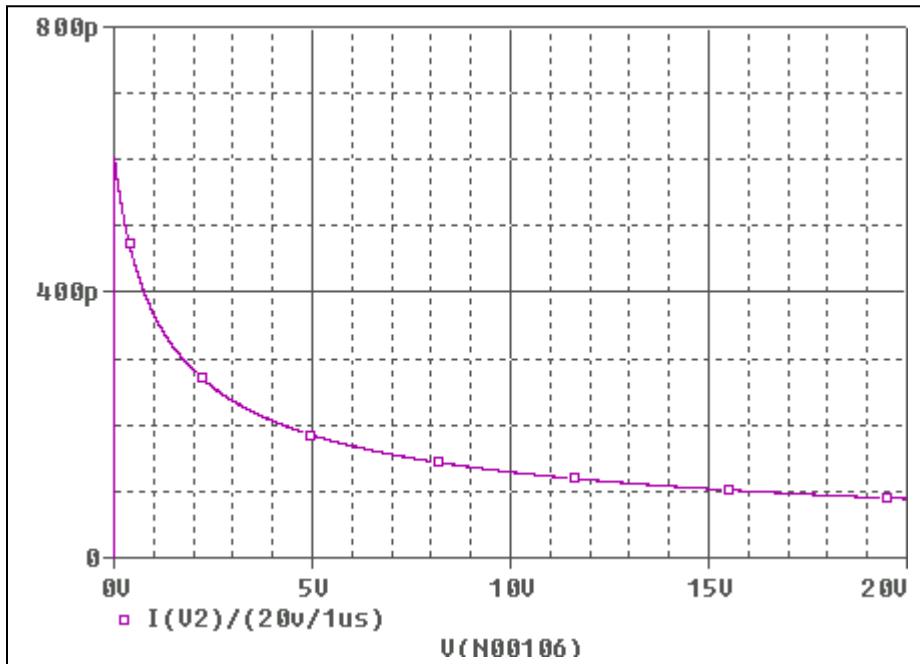


Simulation Result

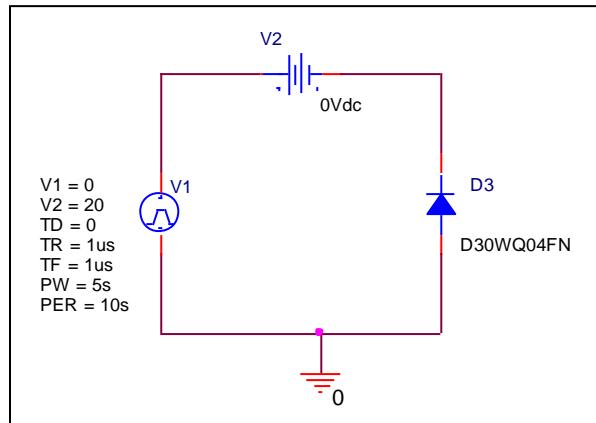
$I_{fwd}$ (A)	$V_{fwd}$ (V) Measurement	$V_{fwd}$ (V) Simulation	%Error
0.01	0.232	0.234	0.85
0.02	0.251	0.252	0.40
0.05	0.278	0.277	-0.36
0.1	0.300	0.296	-1.35
0.2	0.321	0.318	-0.94
0.5	0.355	0.352	-0.85
1	0.386	0.388	0.52
2	0.436	0.442	1.36
5	0.575	0.572	-0.52

## Junction Capacitance Characteristic

### Circuit Simulation Result

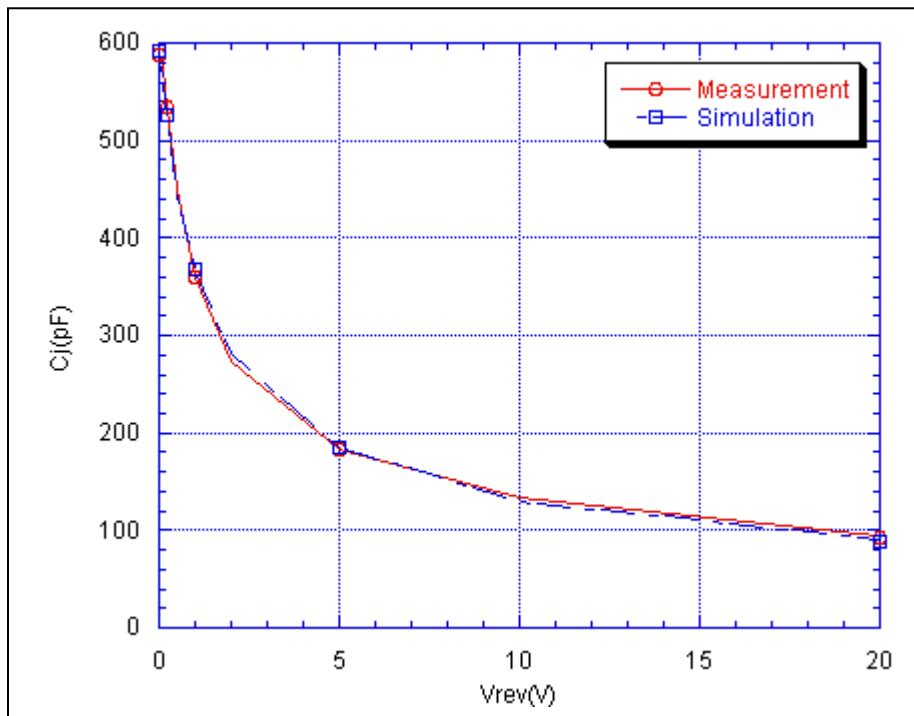


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result



Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
0	588.141	592.184	0.68
0.1	576.447	562.574	-2.47
0.2	534.961	525.717	-1.76
0.5	449.972	446.863	-0.70
1	359.147	367.816	2.36
2	274.144	282.459	2.94
5	182.971	184.818	1.00
10	132.818	129.163	-2.83
20	91.663	88.809	-3.21